SMD Power Inductor

TMPA0603SV-Series(N)-D

	ECN HISTORY LIST							
REV	DATE	DESCRIPTION	APPROVED	CHECKED	DRAWN			
1.0	17/03/16	新發行	楊祥忠	詹偉特	何秦芝			
——————————————————————————————————————			1					
備								
注								

SMD Power Inductor

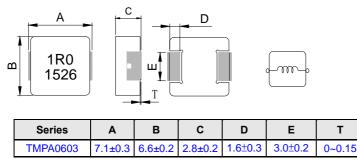
1. Features

- 1. Shielded construction.
- 2. Capable of corresponding high frequency (5MHz).
- 3. Low loss realized with low DCR.
- 4. High performance (Isat) realized by metal dust core.
- 5. Ultra low buzz noise, due to composite construction.
- 6. 100% Lead(Pb)-Free and RoHS compliant.
- 7. High reliability -Reliability test complied to AEC-Q200

2. Applications

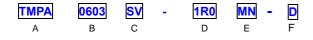
- 1. DC/DC converters in distributed power systems.
- 2. DC/DC converter for Field Programmable Gate Array(FPGA).
- 3. Battery powered devices.
- 4. Thin type on-board power supply module for exchanger.
- 5. VRM for server.
- 6. High current, low profile POL converters.
- 7. PDA/notebook/desktop/server and battery powered devices.

3. Dimensions



Unit:mm

4. Part Numbering



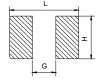
BxC

A: Series

- B: Dimension
- C: Type
- D: Inductance E: Inductance Tolerance
- E: Inductanc F: Code



Recommend PC Board Pattern



L(mm)	G(mm)	H(mm)				
8.0	3.7	3.4				
Note: 1 The above PCB layout reference only						

 Recommend solder paste thickness at 0.15mm and above.

TMPA0603SV-Series(N)-D

5. Specification

Part Number	Inductance L0 A(uH) ±20%	Heat Rating Current DC Typ (A) Irms.	Saturation Current DC Typ (A)I sat	DCR (mΩ)Typ	DCR (mΩ)Max
TMPA0603SV-R15YN-D	0.15±30%	30	40	1.7	2.1
TMPA0603SV-R22MN-D	0.22	23	34	2	2.5
TMPA0603SV-R33MN-D	0.33	21	25	2.8	3.4
TMPA0603SV-R36MN-D	0.36	20	24	3.3	3.9
TMPA0603SV-R47MN-D	0.47	18	20	3.4	4
TMPA0603SV-R56MN-D	0.56	16.5	18	3.9	4.5
TMPA0603SV-R68MN-D	0.68	16	17	4.7	5.3
TMPA0603SV-R82MN-D	0.82	14	16	5.4	6
TMPA0603SV-1R0MN-D	1.00	12	15	6.7	7.4
TMPA0603SV-1R2MN-D	1.20	10	14	7.7	9.5
TMPA0603SV-1R5MN-D	1.50	10	14	10.2	12.1
TMPA0603SV-2R2MN-D	2.20	8	10	13.5	15
TMPA0603SV-2R7MN-D	2.70	7.2	9.8	17.3	20
TMPA0603SV-3R3MN-D	3.30	6.5	9.5	19	22
TMPA0603SV-4R7MN-D	4.70	5.5	6.5	28	33
TMPA0603SV-5R6MN-D	5.60	5.5	6	39	42
TMPA0603SV-6R8MN-D	6.80	4.5	6	43	50
TMPA0603SV-8R2MN-D	8.20	4.5	6	54	60
TMPA0603SV-100MN-D	10.0	4	5.5	62	68
TMPA0603SV-150MN-D	15.0	3	4.5	110	140
TMPA0603SV-220MN-D	22.0	2.5	3	150	190

Note:

1. Test frequency : Ls : 100KHz /1.0V.

2. All test data referenced to $25^\circ\!\!\mathbb{C}$ ambient.

3. Testing Instrument(or equ) : L: HP4284A,CH11025,CH3302,CH1320,CH1320S LCR METER / Rdc:CH16502,Agilent33420A MICRO OHMMETER.

4. Heat Rated Current (Irms) will cause the coil temperature rise approximately $\, \Delta T \, \text{of} \, 40^\circ \! \text{C}$

5. Saturation Current (Isat) will cause L0 to drop approximately 30%.

6. The part temperature (ambient + temp rise) should not exceed 155°C under worst case operating conditions. Circuit design, component, PCB trace size and thickness, airflow and other cooling provisions all affect the part temperature. Part temperature should be verified in the end application.

7. Special inquiries besides the above common used types can be met on your requirement.

6. Material List

	NO	Items	Materials
Marking	1	Core	Alloy Powder .
631	2	Wire	Polyester Wire or equivalent.
	3	Clip	100% Pb free solder(Ni+SnPlating)
	4	Ink	Halogen-free ketone
1 2			

7. Reliability and Test Condition

Item	Performance	Test Condition
Operating temperature	-55~+155℃(Including self - temperature rise)	
Storage temperature and Humidity range	110~+40℃,50~60%RH (Product without taping) 255~+155℃ (on board)	
Electrical Performance	lest .	
Inductance	Refer to standard electrical characteristics list.	HP4284A,CH11025,CH3302,CH1320,CH1320S LCR Meter.
DCR		CH16502, Agilent33420A Micro-Ohm Meter.
Saturation Current (Isat)	Approximately \L30%	Saturation DC Current (Isat) will cause L0 to drop $\bigtriangleup L(\%)$
Heat Rated Current (Irms)	Approximately △T40℃	Heat Rated Current (Irms) will cause the coil temperature rise $\triangle T(\mathbb{C})$. 1.Applied the allowed DC current 2.Temperature measured by digital surface thermometer
Reliability Test		
High Temperature Exposure(Storage)		Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles Temperature : 155±2°C (Inductor) Duration : 1000hrs Min. Measured at room temperature after placing for 24±2 hrs
Temperature Cycling		Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles Condition for 1 cycle Step1 : -55±2℃ 30min Min.(Inductor) Step2 : 155±2℃ transition time 1min MAX. Step3 : 155±2℃ 30min Min. Step4 : Low temp. transition time 1min MAX. Number of cycles : 1000 Measured at room temperature after placing for 24±2 hrs
Moisture Resistance	Appearance : No damage. Inductance : within±10% of initial value Q : Shall not exceed the specification value. RDC : within ±15% of initial value and shall not exceed the specification value	 Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles 1. Baked at50℃ for 25hrs, measured at room temperature after placing for 4 hrs. 2. Raise temperature to 65±2℃ 90-100%RH in 2.5hrs, and keep 3 hours, cool down to 25℃ in 2.5hrs. 3. Raise temperature to 65±2℃ 90-100%RH in 2.5hrs, and keep 3 hours, cool down to 25℃ in 2.5hrs. Keep at 25℃ for 2 hrs then keep at -10℃ for 3 hrs 4. Keep at 25℃ 80-100%RH for 15min and vibrate at the frequency of 10 to 55 Hz to 10 Hz, measure at room temperature after placing for 1–2 hrs.
Biased Humidity (AEC-Q200)		Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles Humidity : 85±3% R.H, Temperature : 85°C±2°C Duration : 1000hrs Min with 100% rated current. Measured at room temperature after placing for24±2 hrs
High Temperature Operational Life (AEC-Q200)		Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles Temperature : 155±2℃(Inductor) Duration : 1000hrs Min. with 100% rated current.
Vibration		Measured at room temperature after placing for24±2 hrs Oscillation Frequency: 10 ~ 2K ~ 10Hz for 20 minute Equipment : Vibration checker Total Amplitude:1.52mm±10% Testing Time : 12 hours(20 minutes, 12 cycles each of 3 orientations)。

ltem	Performance	Test Condition			
		Peak value Normal duration (D) (g's) Wave form Velocity change (Vi)ft/sec			
Mechanical Shock		SMD 100 6 Half-sine 12.3			
SHOCK		Lead 100 6 Half-sine 12.3			
Resistance to Soldering Heat	Appearance:No damage. Impedance:within±15% of initial value Inductance:within±10% of initial value	shocks in each direction along 3 perpendicular axes. Number of heat cycles: 1 Temperature(°C) Time(s) Temperature ramp/immersion and emersion rate 260±5(solder temp) 10±1 25mm/s ±6 mm/s			
Thermal shock	Q : Shall not exceed the specification value. RDC : within $\pm 15\%$ of initial value and shall not exceed the specification value	Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles Condition for 1 cycle Step1 : -55±2°C 15±1min(Inductor) Step2 : 155±2°C within 20Sec. Step3 : 155±2°C 15±1min Number of cycles : 300 Measured at room temperature after placing fo24±2hrs			
Resistance to Solvents	Appearance : No damage.	Add aqueous wash chemical - OKEM clean or equivalent.			
ESD		Vsurge 0.63 ^{rv} surge 0.37 ^{rv} surge $T_c = charge time constant$ $T_d = discharge time$ $T_c = charge time constant$ $T_d = discharge time$ $T_c = charge time constant$ $T_d = discharge time$ $T_c = charge time constant$			
Solderability	More than 95% of the terminal electrode should be covered with solder。	Steam Aging: 8 hours ± 15 min Preheat: 150℃,60sec.₀ Solder: Sn96.5% Ag3% Cu0.5% Temperature: 245±5℃。 Flux for lead free: Rosin. 9.5%。 Dip time: 4±1sec. Depth: completely cover the termination			
	Electrical Test not required	V-0 or V-1 are acceptable			
Flammability					

Performance	Test Condition
	Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles Place the 100mm X 40mm board into a fixture similar to the one shown in below Figure with the component facing down. The apparatus shall consist of mechanical means to apply a force which will bend the board (D) $x = 2$ mm minimum. The duration of the applied forces shall be 60 (+ 5) sec. The force is to be applied only once to the board.
Appearance : No damage.	Professional from the analysis of the second
	Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J.STD-020D Classification Reflow Profiles With the component mounted on a PCB with the device to be tested, apply a 17.7 N (1.8 Kg) force to the side of a device being tested. This force shall be applied for 60 +1 seconds. Also the force shall be applied gradually as not to apply a shock to the component being tested.

Note : When there are questions concerning measurement result : measurement shall be made after 48 ± 2 hours of recovery under the standard condition.

8. Soldering and Mounting

(1) Soldering

Mildly activated rosin fluxes are preferred. The minimum amount of solder can lead to damage from the stresses caused by the difference in coefficients of expansion between solder, chip and substrate. TAI-TECH terminations are suitable for re-flow soldering systems. If hand soldering cannot be avoided, the preferred technique is the utilization of hot air soldering tools.

(2) Solder re-flow:

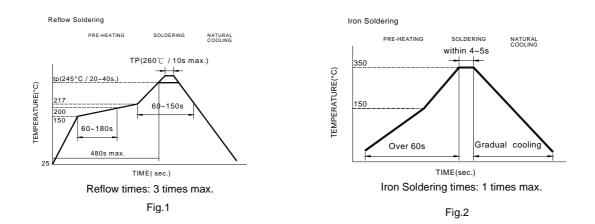
Recommended temperature profiles for re-flow soldering in Figure 1.

(3) Soldering Iron:

Products attachment with a soldering iron is discouraged due to the inherent process control limitations. In the event that a soldering iron must be employed the following precautions are recommended.

- Preheat circuit and products to $150^\circ\!\mathrm{C}$ · Never contact the ceramic with the iron tip · 355℃ tip temperature (max)
 - · 1.0mm tip diameter (max)

 Use a 20 watt soldering iron with tip diameter of 1.0mm · Limit soldering time to 4~5sec.

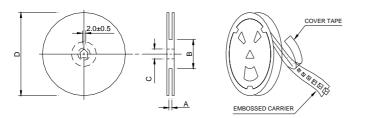


9. Friendly reminder

- (1) When there are questions concerning measurement result : measurement shall be made after 48 \pm 2 hours of recovery under the standard condition
- (2) This power choke coil itself does not have any protective function in abnormal condition such as overload, short-circuit and open-circuit conditions, etc. Therefore, it shall be confirmed as the end product that there is no risk of smoking, fire, dielectric withstand voltage, insulation resistance, etc. in abnormal conditions to provide protective devices and/or protection circuit in the end product.
- (3) When this power choke coil was used in a similar or new product to the original one, sometimes it might not be able to satisfy the specifications due to different condition of use.
- (4) Dielectric withstanding test with higher voltage than specific value will damage insulating material and shorten its life.
- (5) This power choke coil must not be used in wet condition by water, coffee or any liquid because insulation strength becomes very low in this condition.
- (6) Please consult our company to confirm the reliability of the process required to wash or use or exposure to a chemical solvent used in this product.

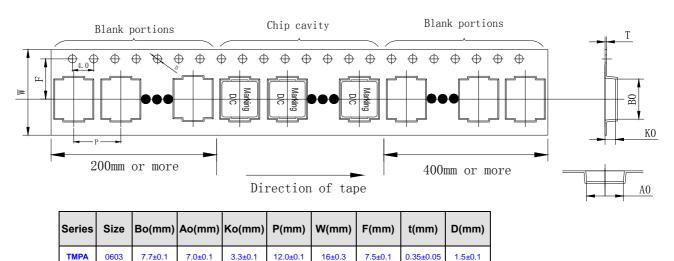
10. Packaging Information

(1) Reel Dimension



Туре	A(mm)	B(mm)	C(mm)	D(mm)
13"x16mm	16.4+2/-0	100±2	13+0.5/-0.2	330

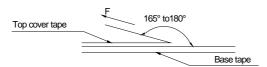
(2) Tape Dimension



(3) Packaging Quantity

TMPA	0603
Chip / Reel	1000
Inner box	2000
Carton	8000

(4) Tearing Off Force



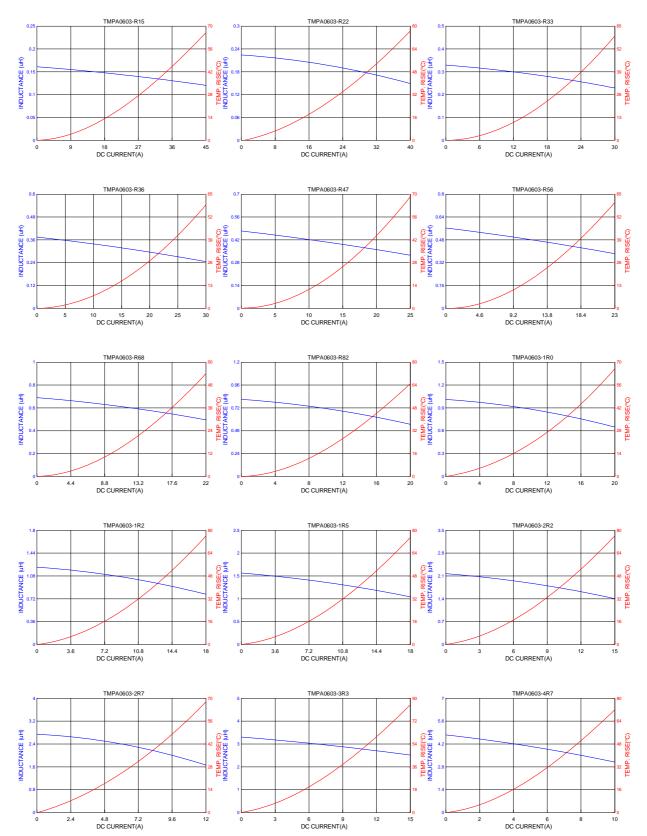
The force for tearing off cover tape is 10 to 130 grams in the arrow direction under the following conditions(referenced ANSI/EIA-481-C-2003 of 4.11 standard).

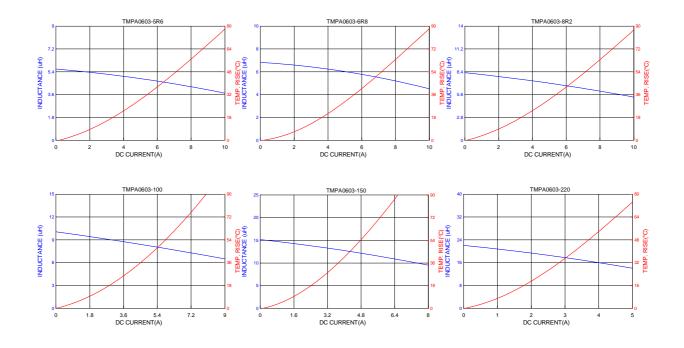
Room Temp. (℃)	Room Temp.Room Humidity(°C)(%)		Tearing Speed mm/min		
5~35	45~85	860~1060	300		

Application Notice

- Storage Conditions(component level)
 To maintain the solderability of terminal electrodes:
- 1. TAI-TECH products meet IPC/JEDEC J-STD-020D standard-MSL, level 1.
- 2. Temperature and humidity conditions: Less than 40 $^\circ\!\mathrm{C}$ $\,$ and 60% RH.
- 3. Recommended products should be used within 12 months form the time of delivery.
- 4. The packaging material should be kept where no chlorine or sulfur exists in the air.
- Transportation
- 1. Products should be handled with care to avoid damage or contamination from perspiration and skin oils.
- 2. The use of tweezers or vacuum pick up is strongly recommended for individual components.
- 3. Bulk handling should ensure that abrasion and mechanical shock are minimized.

11. Typical Performance Curves









號碼(No.): CE/2016/A0549 E

日期(Date): 2016/10/13

頁數(Page): 1 of 12

Test Report

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO., LTD.)

(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件(泗洪)有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

桃園市楊梅區幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI, TAO-YUAN CITY, TAIWAN, R. O. C.)

(江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園市中壢區中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN) (中國江蘇省宿邊市泗洪縣經濟開發區杭州路南側建設北路東側 / THE SOUTH HANGZHOU ROAD AND THE EAST JIANSHE ROAD, ECONOMIC DEVELOPMENT ZONE, SIHONG COUNTY, SUQIANCITY, JIANGSU PROVINCE, P. R. CHINA)

以下測試樣品係由申請廠商所提供及確認 (The following sample(s) was/were submitted and identified by/on behalf of the applicant as):

樣品名稱(Sample Description)	:	SMD POWER INDUCTOR
樣品型號(Style/Item No.)	:	TMPB、TMPC、TMPA、TMPF、SLPI、SMPI、EPI(ePI)、VMPI、MLPI SERIES
收件日期(Sample Receiving Date)	:	2016/10/05
測試期間(Testing Period)	:	2016/10/05 TO 2016/10/13

測試需求(Test Requested):

 (1) 依據客戶指定,參考RoHS2011/65/EU Annex II及其修訂指令(EU) 2015/863測試鍋、鉛、汞、六價絡、多溴聯 苯、多溴聯苯醚, DBP, BBP, DEHP, DIBP. (As specified by client, with reference to RoHS 2011/65/EU Annex II and amending Directive (EU) 2015/863 to determine Cadmium, Lead, Mercury, Cr(VI), PBBs, PBDEs, DBP, BEP, DEHP, DIBP contents in the submitted sample.)

(2) 其他測試項目請見下一頁 . (Please refer to next pages for the other item(s).)

測試結果(Test Results) : 請見下一頁 (Please refer to next pages).



This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at http://www.sgs.com/en/Terms-and-Conditions.aspx and, for electronic format documents, subject to Terms and Conditions for Electronic Documents at <a href="http://www.sgs.com/en/Terms-and-Conditions/Terms-an



Test Report

號碼(No.): CE/2016/A0549 E

日期(Date) : 2016/10/13

頁數(Page): 2 of 12

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO., LTD.)

(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件(泗洪)有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

桃園市楊梅區幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI, TAO-YUAN CITY, TAIWAN, R. O. C.)

(江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園市中壢區中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN) (中國江蘇省宿遷市泗洪縣經濟開發區杭州路南側建設北路東側 / THE SOUTH HANGZHOU ROAD AND THE EAST JIANSHE ROAD, ECONOMIC DEVELOPMENT ZONE, SIHONG COUNTY, SUQIANCITY, JIANGSU PROVINCE, P. R. CHINA)

<u>測試結果(Test Results)</u>

測試部位(PART NAME)No.1 : 整體混測 (MIXED ALL PARTS)

結果 方法偵測 單位 测試方法 測試項目 極限值 (Result) (Test Items) (Unit) (Method) (MDL) No. 1 參考IEC 62321-5 (2013),以感應耦合 9 n. d. 鎘 / Cadmium (Cd) mg/kg 電漿原子發射光譜儀檢測. / With reference to IEC 62321-5 (2013) and performed by ICP-AES. 鉛 / Lead (Pb) 參考IEC 62321-5 (2013),以感應耦合 2 n. d. mg/kg 電漿原子發射光譜儀檢測. / With reference to IEC 62321-5 (2013) and performed by ICP-AES. 参考IEC 62321-4 (2013),以感應耦合 2 n. d. 汞 / Mercury (Hg) mg/kg 電漿原子發射光譜儀檢測. / With reference to IEC 62321-4 (2013) and performed by ICP-AES. 参考IEC 62321 (2008),以UV-VIS檢 2 n. d. 六價鉻 / Hexavalent Chromium Cr(VI) mg/kg 测, / With reference to IEC 62321 (2008) and performed by UV-VIS. 参考US EPA 3052 (1996),以感應耦合 9 n. d. 鈹 / Beryllium (Be) mg/kg 電漿原子發射光譜儀檢測. / With reference to US EPA 3052 (1996). Analysis was performed by ICP-AES. 參考US EPA 3052 (1996),以感應耦合 2銻 / Antimony (Sb) mg/kg n. d. 電漿原子發射光譜儀檢測. / With reference to US EPA 3052 (1996). Analysis was performed by ICP-AES.

This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at <a href="http://www.ags.com/en/Terms-and-Conditions-ageneration-service-printed-conditions-ageneration-service-printed-conditions-ageneration-service-printed-conditions-company-service-printed-company-service-printed-conditions-company-service-printed-company-service-printed-company-service-printed-conditions-company-service-printed-conditions-company-service-printed-conditions-company-service-printed-conditions-company-service-printed-conditions-company-service-printed-conditions-company-service-printed-conditions-company-service-printed-conditions-company-service-printed-conditions-company-service-printed-company-service-printed-company-service-printed-company-service-printed-company-service-printed-conditions-company-service-printed-company-service

SGS Taiwan Ltd. 台灣檢验科技股份有限公司 125, Wu Chyuan 7th Road, New Taipei Industrial Park, Wu Ku District, New Taipei City, Taiwan,新北市五股區新北產期間區五龍七路25號

SG

號碼(No.): CE/2016/A0549 日期(Date

日期(Date): 2016/10/13

頁數(Page): 3 of 12

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO., LTD.)

(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件(泗洪)有限公司 / TAIPAQ ELECTRONICS(SI-HONG)CO., LTD.)

桃園市楊梅區幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI, TAO-YUAN CITY, TAIWAN, R. O. C.)

(江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園市中壢區中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN) (中國江蘇省宿還市泗洪縣經濟開發區杭州路南側建設北路東側 / THE SOUTH HANGZHOU ROAD AND THE EAST JIANSHE ROAD, ECONOMIC DEVELOPMENT ZONE, SIHONG COUNTY, SUQIANCITY, JIANGSU PROVINCE, P. R. CHINA)

測試項目 (Test Items)	單位 (Unit)	測試方法 (Method)	方法偵測 極限值 (MDL)	結果 (Result) No.1
六溴環十二烷及所有主要被辨別出的異構 物 / Hexabromocyclododecane (HBCDD) and all major diastereoisomers identified (α - HBCDD, β - HBCDD, γ - HBCDD) (CAS No.: 25637-99-4 and 3194-55-6 (134237-51-7, 134237-50-6, 134237-52-8))	mg/kg	參考IEC 62321 (2008),以魚相層析/ 質譜儀檢測. / With reference to IEC 62321 (2008). Analysis was performed by GC/MS.	5	n. d.
鹵素 / Halogen				
鹵素(氟)/ Halogen-Fluorine (F) (CAS No.: 14762-94-8)	mg/kg		50	n.d.
鹵素(氯)/ Halogen-Chlorine(C1) (CAS No.: 22537-15-1)	mg/kg	參考BS EN 14582(2007),以離子層析 儀分析. / With reference to BS EN	50	n. d.
鹵素(溴)/ Halogen-Bromine (Br) (CAS No.: 10097-32-2)	mg/kg	14582 (2007). Analysis was performed by IC.	50	n. d.
鹵素 (碘) / Halogen-Iodine (I) (CAS No.: 14362-44-8)	mg/kg		50	n. d.
鄰苯二甲酸丁苯甲酯 / BBP (Butyl Benzyl phthalate) (CAS No.: 85-68-7)	mg/kg	參考IEC 62321-8/CD (2013),以氣相	50	n. d.
鄰苯二甲酸二丁酯 / DBP (Dibutyl phthalate) (CAS No.: 84-74-2)	mg/kg	層析儀/質譜儀檢測. / With reference to IEC 62321-8/CD	50	n. d.
鄰苯二甲酸二 (2-乙基己基)酯 / DEHP (Di- (2-ethylhexyl) phthalate) (CAS No.: 117-81-7)	mg/kg	(2013). Analysis was performed by GC/MS.	50	n. d.

This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at http://www.gg.com/ser/Terms-and-Conditions and, for electronic format documents, subject to Terms and Conditions for Electronic Documents at <a href="http://www.gg.com/ser/Terms-and-Conditions/Terms-and-Conditio

SGS Taivvan Ltd. 台灣檢驗科技股份有限公司 125, Wu Chyuan 7th Road, New Taipei Industrial Park, Wu Ku District, New Taipei City, Taiwan 册北市五股區新准產業園區五種上路26號



號碼(No.): CE/2016/A0549 日期(Date): 2016/10/13

頁數(Page): 4 of 12

Test Report

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO., LTD.)

(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件(泗洪)有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

桃園市楊梅區幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI, TAO-YUAN CITY, TAIWAN, R. O. C.)

(江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園市中壢區中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN) (中國江蘇省宿還市泗洪縣經濟開發區杭州路南側建設北路東側 / THE SOUTH HANGZHOU ROAD AND THE EAST JIANSHE ROAD, ECONOMIC DEVELOPMENT ZONE, SIHONG COUNTY, SUQIANCITY, JIANGSU PROVINCE, P. R. CHINA)

測試項目 (Test Items)	單位 (Unit)	測試方法 (Method)	方法偵測 極限值 (MDL)	結果 (Result) No.1
鄰苯二甲酸二異丁酯 / DIBP (Di-isobuty1 phthalate) (CAS No.: 84-69-5)	mg/kg	參考IEC 62321-8/CD (2013),以氣相 層析儀/質譜儀檢測. / With reference to IEC 62321-8/CD (2013). Analysis was performed by GC/MS.	50	n. d.
鄰苯二甲酸二異癸酯 / DIDP (Di-isodecyl phthalate) (CAS No.: 26761-40-0; 68515-49-1)	mg/kg		50	n. d.
鄰苯二甲酸二異壬酯 / DINP (Di-isonony1 phthalate) (CAS No.: 28553-12-0; 68515-48-0)	mg/kg		50	n. d.
鄰苯二甲酸二正辛酯 / DNOP (Di-n-octyl phthalate) (CAS No.: 117-84-0)	mg/kg		50	n. d.
鄭苯二甲酸二正已酯 / DNHP (Di-n-hexyl phthalate) (CAS No.: 84-75-3)	mg/kg		50	n. d.
鄰苯二甲酸二戊酯 / Di-n-pentyl phthalate (CAS No.: 131-18-0)	mg/kg		50	n. d.
多溴聯苯總和 / Sum of PBBs	mg/kg	參考IEC 62321-6 (2015),以氣相層析 /質譜儀檢測. / With reference to IEC 62321-6 (2015) and performed by GC/MS.	-	n. d.
一溴聯苯 / Monobromobiphenyl	mg/kg		5	n. d.
二溴聯苯 / Dibromobiphenyl	mg/kg		5	n.d.
三溴聯苯 / Tribromobiphenyl	mg/kg		5	n.d.
四溴聯苯 / Tetrabromobiphenyl	mg/kg		5	n. d
五溴聯苯 / Pentabromobiphenyl	mg/kg		5	n. d.
六溴聯苯 / Hexabromobiphenyl	mg/kg		5	n. d.
七溴聯苯 / Heptabromobiphenyl	mg/kg		5	n. d.
八溴聯苯 / Octabromobiphenyl	mg/kg		5	n. d
九溴聯苯 / Nonabromobiphenyl	mg/kg		5	n. d.
十溴聯苯 / Decabromobiphenyl	ng/kg		5	n. d.

This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at http://www.ega.com/en/Terms-and-Conditions asnx and, for electronic format documents, subject to Terms and Conditions for Electronic Documents at http://www.ega.com/en/Terms-and-Conditions/Terms-Ad-Conditio

SGS Taivvan L1d. 台湾徐璇科技股份有限公司 125, Wu Chyuan 7th Road, New Taipel Industrial Park, Wu Ku District, New Taipei City, Taiwan 新北市1股區新北產業園區12是1826號



號碼(No.) : CE/2016/A0549

日期(Date): 2016/10/13

頁數(Page): 5 of 12

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD. (臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO., LTD.)

(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件(泗洪)有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

桃園市楊梅區幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI, TAO-YUAN CITY, TAIWAN, R. O. C.)

(江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園市中壢區中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN) (中國江蘇省宿還市泗洪縣經濟開發區杭州路南側建設北路東側 / THE SOUTH HANGZHOU ROAD AND THE EAST JIANSHE ROAD, ECONOMIC DEVELOPMENT ZONE, SIHONG COUNTY, SUQIANCITY, JIANGSU PROVINCE, P. R. CHINA)

測試項目 (Test Items)	單位 (Unit)	测試方法 (Method)	方法偵測 極限值 (MDL)	結果 (Result) No.1
多溴聯苯醚總和 / Sum of PBDEs	mg/kg	参考IEC 62321-6 (2015),以魚相層析 /質譜儀檢測. / With reference to IEC 62321-6 (2015) and performed by GC/MS.		n.d.
一溴聯苯醚 / Monobromodiphenyl ether	mg/kg		5	n. d.
二溴聯苯醚 / Dibromodiphenyl ether	mg/kg		5	n.d.
三溴聯苯醚 / Tribromodiphenyl ether	mg/kg		5	n.d.
四溴聯苯醚 / Tetrabromodiphenyl ether	mg/kg		5	n d
五溴聯苯醚 / Pentabromodiphenyl ether	mg/kg		5	n. d.
六溴聯苯醚 / Hexabromodiphenyl ether	mg/kg		5	n. d.
七溴聯苯醚 / Heptabromodiphenyl ether	mg/kg		5	n. d.
八溴聯苯醚 / Octabromodiphenyl ether	mg/kg		5	n. d.
九溴聯苯醚 / Nonabromodiphenyl ether	mg/kg		5	n.d.
十溴聯苯醚 / Decabromodiphenyl ether	mg/kg		5	n. d.

備註(Note):

1. mg/kg = ppm : 0. 1wt% = 1000ppm

2. n.d. = Not Detected (未檢出)

3. MDL = Method Detection Limit (方法偵測極限值)

4. "-" = Not Regulated (無規格值)

This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at http://www.sgs.com/en/Terms-and-Conditions aspx. Ind, for electronic format documents, subject to Terms and Conditions for Electronic Documents at <a href="http://www.sgs.com/en/Terms-and-Conditions/Terms-and-Co



Test Report

號碼(No.): CE/2016/A0549 日期(Date): 2016/10/13

頁數(Page): 6 of 12

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

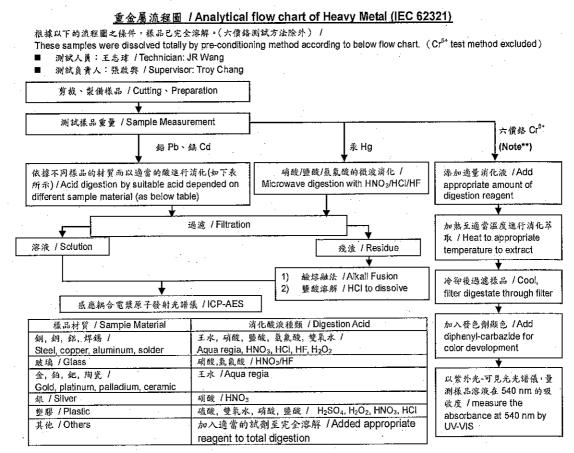
(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO., LTD.)

(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件 (泗洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

桃園市楊梅區幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI, TAO-YUAN CITY, TAIWAN, R. O. C.)

(江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園市中壢區中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN) (中國江蘇省宿還市泗洪縣經濟開發區杭州路南側建設北路東側 / THE SOUTH HANGZHOU ROAD AND THE EAST JIANSHE ROAD, ECONOMIC DEVELOPMENT ZONE, SIHONG COUNTY, SUQIANCITY, JIANGSU PROVINCE, P. R. CHINA)



Note**: (1) 針對非金屬材料加入鹼性消化液,加熱至 90~95℃ 萃取. / For non-metallic material, add alkaline digestion reagent and heat to 90~95℃.

(2) 針對金屬材料加入純水,加熱至沸腾萃取. / For metallic material, add pure water and heat to boiling

This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at http://www.sgs.com/en/Terms.and.Conditions.aspx. and, for electronic format documents, subject to Terms and Conditions for Electronic Documents at http://www.sgs.com/en/Terms.end-Conditions/Terms.ond-Conditions for Electronic Documents at http://www.sgs.com/en/Terms.end-Conditions/Terms.ond-Conditions for Electronic Documents at http://www.sgs.com/en/Terms.end-Conditions/Terms.ond-Conditions for Electronic Documents at http://www.sgs.com/en/Terms.end-Conditions/Terms.ond/Terms.ond-Conditions/Terms.ond-Conditions/Te

SGS Taiwan Ltd. 台灣檢验科技現份有限公司 | 25, Wu Chyuan 7th Road, New Taipel Industrial Park, Wu Ku District, New Taipei City, Taiwan 新北市近韓區新北產業團區五雅七路25號



號碼(No.) : CE/2016/A0549

日期(Date): 2016/10/13

頁數(Page): 7 of 12

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO., LTD.)

(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件(泗洪)有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

桃園市楊梅區幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI, TAO-YUAN CITY, TAIWAN, R. O. C.)

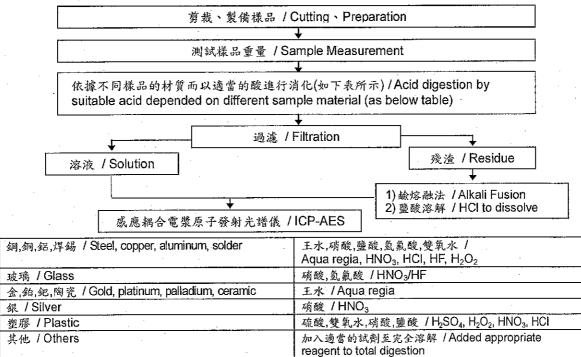
(江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園市中壢區中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN) (中國江蘇省宿遷市泗洪縣經濟開發區杭州路南側建設北路東側 / THE SOUTH HANGZHOU ROAD AND THE EAST JIANSHE ROAD, ECONOMIC DEVELOPMENT ZONE, SIHONG COUNTY, SUQIANCITY, JIANGSU PROVINCE, P. R. CHINA)

根據以下的流程圖之條件,樣品已完全溶解。 / These samples were dissolved totally by pre-conditioning method according to below flow chart.

- 測試人員:王志瑋 / Technician: JR Wang
- 測試負責人:張啟興 / Supervisor: Troy Chang

元素以 ICP-AES 分析的消化流程圖

(Flow Chart of digestion for the elements analysis performed by ICP-AES)



This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at http://www.gos.com/en/Terms-and-Conditions/aspx and, for electronic format documents, subject to Terms and Conditions for Electronic Documents at http://www.gos.com/en/Terms-and-Conditions/Terms-abccurriert.aspx. Attention is drawn to the limitation of liability, indemnification and jurisdiction issues defined therein. Any holder of this document is actived that information contained hereion reflects the Company's findings at the time of its intervention only and within the limits of client's instruction, if any. The Company's sole responsibility is to its Client and this document does not exonerate parties to a transaction from exercising all their rights and obligations under the transaction documents. This document cannot be reproduced, except in full, without prior written approval of the Company. Any unauthorized alteration, forgery or falsification of the content or appearance of this document is unlawful and offenders may be prosecuted to the fullest extent of the law. Unless otherwise stated the results shown in this test report refer only to the sample(s) tested.



號碼(No.): CE/2016/A0549 日期(Date): 2016/10/13

頁數(Page): 8 of 12

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO., LTD.)

(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件(泗洪)有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

桃園市楊梅區幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI, TAO-YUAN CITY, TAIWAN, R. O. C.)

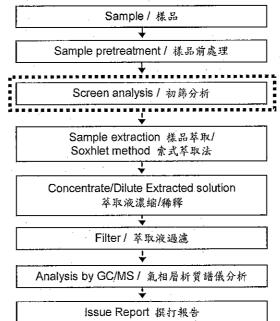
(江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園市中壢區中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN) (中國江蘇省宿還市泗洪縣經濟開發區杭州路南側建設北路東側 / THE SOUTH HANGZHOU ROAD AND THE EAST JIANSHE ROAD, ECONOMIC DEVELOPMENT ZONE, SIHONG COUNTY, SUQIANCITY, JIANGSU PROVINCE, P. R. CHINA)

多溴聯苯/多溴聯苯醚分析流程圖 / Analytical flow chart - PBB/PBDE

測試人員:涂雅苓 / Technician: Yaling Tu

測試負責人:張啟興 / Supervisor: Troy Chang

初次測試程序 / First testing process . 選擇性篩檢程序 / Optional screen process = = = 確認程序 / Confirmation process -----



This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at http://www.sgs.com/en/Terms-and-Conditions aspx and, for electronic format documents, subject to Terms and Conditions for Electronic Documents at <a href="http://www.sgs.com/en/Terms-and-Conditions/Terms-Brownent/Terms-and-Conditions/Terms-Brownent/Terms-and-Conditions/Terms-Brownent

SGS Taiwan Ltd. 台灣檢驗科技股份有態公司 25.Wu Chyuan 7th Road, New Taipei Industrial Park, Wu Ku District, New Taipei City, Taiwan 新北市工程區新北產業園區工程七路25號



號碼(No.) : CE/2016/A0549

日期(Date): 2016/10/13

頁數(Page): 9 of 12

rest Report

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO., LTD.)

(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件(泗洪)有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

桃園市楊梅區幼獅工業區幼四路1號 / NO. 1,YOU 4TH ROAD,YOUTH INDUSTRIAL DISTRICT,YANG-MEI,TAO-YUAN CITY, TAIWAN,R. O. C.)

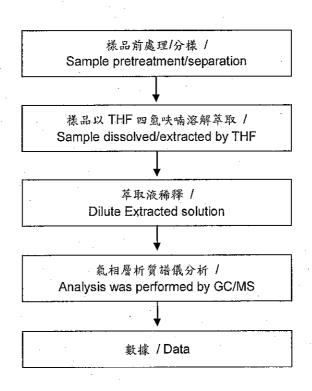
(江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園市中壢區中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN) (中國江蘇省宿遷市泗洪縣經濟開發區杭州路南側建設北路東側 / THE SOUTH HANGZHOU ROAD AND THE EAST JIANSHE ROAD, ECONOMIC DEVELOPMENT ZONE, SIHONG COUNTY, SUQIANCITY, JIANGSU PROVINCE, P. R. CHINA)

可塑劑分析流程圖 / Analytical flow chart - Phthalate

■ 测試人員:徐毓明 / Technician: Andy Shu

■ 测試負責人:張啟興 / Supervisor: Troy Chang

【测試方法/Test method: IEC 62321-8】



This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at http://www.egs.com/en/Terms.and/Conditions for Electronic Documents at http://www.egs.com/en/Terms.and/Conditions for Electronic Documents at http://www.egs.com/en/Terms.and/Conditions for Electronic Documents at http://www.egs.com/en/Terms.and/Conditions/Terms.and/Conditions for Electronic Documents at http://www.egs.com/en/Terms.and/Conditions/Terms.and/Conditions/ For Electronic Documents at http://www.egs.com/en/Terms.and/Conditions/Terms.and/Condit

- SGS Taiwan Ltd. 台灣檢驗科技股份有態公司 25, Wu Chyuan 7th Road, New Taipei Industrial Park, Wu Ku District, New Taipei City, Taiwan 新北市五碳區新北產獎團區五推上路25號



Test Report

號碼(No.):CE/2016/A0549

日期(Date): 2016/10/13

頁數(Page): 10 of 12

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO., LTD.)

(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件(泗洪)有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

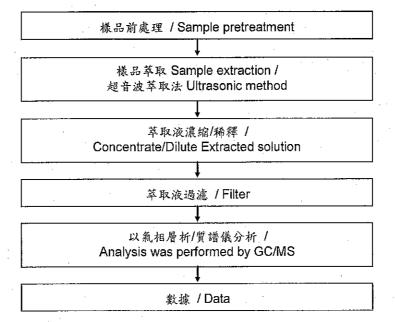
桃園市楊梅區幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI, TAO-YUAN CITY, TAIWAN, R. O. C.)

(江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園市中壢區中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN) (中國江蘇省宿還市泗洪縣經濟開發區杭州路南側建設北路東側 / THE SOUTH HANGZHOU ROAD AND THE EAST JIANSHE ROAD, ECONOMIC DEVELOPMENT ZONE, SIHONG COUNTY, SUQIANCITY, JIANGSU PROVINCE, P. R. CHINA)

六溴環十二烷分析流程圖 / Analytical flow chart - HBCDD

■ 測試人員:凃雅苓 / Technician: Yaling Tu

■ 測試負責人:張啟興 / Supervisor: Troy Chang



This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at http://www.sgs.com/en/Terms-and-Conditions.aspx and, for electronic format documents, subject to Terms and Conditions for Electronic Documents at http://www.sgs.com/en/Terms-and-Conditions.aspx drawn to the limitation of liability, indemnification and jurisdiction issues defined therein. Any holder of this document is advised that information contained hereon relacts the Company's findings at the time of its intervention only and within the limits of client" is instruction, if any. The Company's sole responsibility is to its Client and this document document to a spearance of this document cannot be reproduced, except in full, without prior written approval of the Company. Any unauthorized alteration, forgery or relativistion of the content or appearance of this document is unlawful and offenders may be prosecuted to the fullest extent of the law. Unless otherwise stated the results shown in this test report refer only to the sample(s) tested.

- SGS Taitvoart Ltd. 台灣檢驗科技股份有限公司 155, Wu Chyuan 7th Road, New Taipei Industrial Park, Wu Ku District, New Taipei City, Taiwan 新北市近親医新北產業園區工程上路25號

SG

號碼(No.) : CE/2016/A0549

日期(Date) : 2016/10/13 .

頁數(Page): 11 of 12

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO., LTD.)

(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件(泗洪)有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

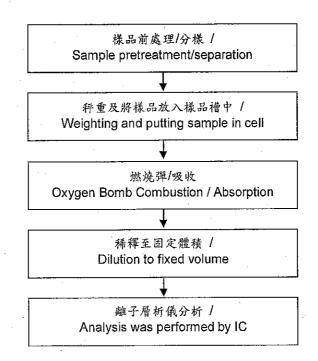
桃園市楊梅區幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI, TAO-YUAN CITY, TAIWAN, R. O. C.)

(江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園市中壢區中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN) (中國江蘇省宿遷市泗洪縣經濟開發區杭州路南側建設北路東側 / THE SOUTH HANGZHOU ROAD AND THE EAST JIANSHE ROAD, ECONOMIC DEVELOPMENT ZONE; SIHONG COUNTY, SUQIANCITY, JIANGSU PROVINCE, P. R. CHINA)

<u> 鹵素分析流程圖 / Analytical flow chart - Halogen</u>

■ 测試人員:陳恩臻 / Technician: Rita Chen

■ 測試負責人:張啟興 / Supervisor: Troy Chang



This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at http://www.sas.com/en/Terms-and-Conditions.aspx. and, for electronic format documents, subject to Terms and Conditions for Electronic Documents at http://www.sas.com/en/Terms-and-Conditions/Terms-Document.aspx. Attention is drawn to the limitation of liability, indemnification and jurisdiction issues defined therein. Any holder of this document is advised that information contained hereon reflects the Company's findings at the time of its intervention only and within the limits of client's instruction, if any. The Company's sole responsibility is to its Client and this document does not excende the transaction documents. This document cannot be reproduced, except in full, without prior written approval of the Company. Any unauthorized alteration, forgery or falsification of the content or appearance of this document is unlawful and offenders may be prosecuted to the fullest extent of the law. Unless otherwise stated the results shown in this test report refer only to the sample(s) tested.

SGS Taiwan Ltd. 台湾 決除料技股份有限公司 125, Wu Chyuan 7th Road, New Taipei Industrial Park, Wu Ku District, New Taipei City, Taiwan 新北市五板區新北產架園區五板七路25號



號碼(No.) : CE/2016/A0549

日期(Date): 2016/10/13 頁數(Page): 12 of 12

Test Report

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO., LTD.)

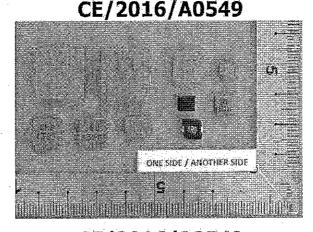
(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件(泗洪)有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

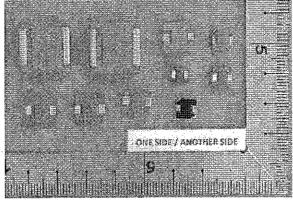
桃園市楊梅區幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI, TAO-YUAN CITY, TAIWAN, R. O. C.)

(江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園市中壢區中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN) (中國江蘇省宿遷市泗洪縣經濟開發區杭州路南側建設北路東側 / THE SOUTH HANGZHOU ROAD AND THE EAST JIANSHE ROAD, ECONOMIC DEVELOPMENT ZONE, SIHONG COUNTY, SUQIANCITY, JIANGSU PROVINCE, P. R. CHINA)

> * 照片中如有箭頭標示,則表示為實際檢測之樣品/部位. * (The tested sample / part is marked by an arrow if it's shown on the photo.)



CE/2016/A0549



** 報告結尾 (End of Report) **

This document is issued by the Company subject to its General Conditions of Service printed overleaf, available on request or accessible at http://www.sgs.com/en/Terms-and-Conditions of Service printed overleaf, available on request or accessible at http://www.sgs.com/en/Terms-and-Conditions service printed overleaf, available on request or accessible at http://www.sgs.com/en/Terms-and-Conditions service printed overleaf, available on request or accessible at http://www.sgs.com/en/Terms-and-Conditions service printed overleaf, available on request or accessible at http://www.sgs.com/en/Terms-and-Conditions service printed overleaf, available on request or accessible at http://www.sgs.com/en/Terms-and-Conditions service printed overleaf, available on request or accessible at http://www.sgs.com/en/Terms-and-Conditions service printed overleaf, available on request or accessible at http://www.sgs.com/en/Terms-and-Conditions service printed overleaf, available on request or accessible at http://www.sgs.com/en/Terms-and-Conditions service printed overleaf, available on request or accessible at http://www.sgs.com/en/Terms-and-Conditions service printed overleaf, available on request or accessible at http://www.sgs.com/en/Terms-and-Conditions service printed overleaf, available on request at http://www.sgs.com/en/Terms-and-Con

SGS Tarvan Ltd. 台灣檢驗科技眼份有態公司 25, Wu Chyuan 7th Road, Naw Taipei Industrial Park, Wu Ku District, New Taipei City, Taiwan 新北市五戰輻射北產業園區五根七路25艘 1+886 (02)2299 3939 (+886 (02)2299 3237 www.sos.tw

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Fixed Inductors category:

Click to view products by Tai-Tech manufacturer:

Other Similar products are found below :

MLZ1608M6R8WTD25 MLZ1608N6R8LT000 MLZ1608N3R3LTD25 MLZ1608N3R3LT000 MLZ1608N150LT000 MLZ1608M150WTD25 MLZ1608M3R3WTD25 MLZ1608M3R3WT000 MLZ1608M150WT000 MLZ1608A1R5WT000 MLZ1608N1R5LT000 B82432C1333K000 PCMB053T-1R0MS PCMB053T-1R5MS PCMB104T-1R5MS CR32NP-100KC CR32NP-151KC CR32NP-180KC CR32NP-181KC CR32NP-1R5MC CR32NP-390KC CR32NP-3R9MC CR32NP-680KC CR32NP-820KC CR32NP-8R2MC CR43NP-390KC CR43NP-560KC CR43NP-680KC CR54NP-181KC CR54NP-470LC CR54NP-820KC CR54NP-8R5MC ET3542-057 MGDQ4-00004-P MGDU1-00016-P MHL1ECTTP18NJ MHL1JCTTD12NJ PE-51506NL PE-53601NL PE-53630NL PE-53824SNLT PE-62892NL PE-92100NL PG0434.801NLT PG0936.113NLT PM06-2N7 PM06-39NJ HC2LP-R47-R HC2-R47-R HC3-2R2-R